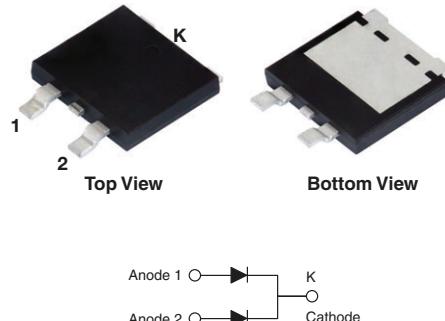


## Dual TMBS® (Trench MOS Barrier Schottky) Rectifier

Ultra Low  $V_F$  = 0.55 V at  $I_F$  = 5 A

### eSMP® Series SMPD (TO-263AC)



### FEATURES

- Trench MOS Schottky technology
- Very low profile - typical height of 1.7 mm
- Ideal for automated placement
- Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak M3 of 260 °C
- AEC-Q101 qualified available:
  - Automotive ordering code: base P/NHM3
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)

 AUTOMOTIVE GRADE Available



 RoHS  
COMPLIANT  
HALOGEN  
FREE

### LINKS TO ADDITIONAL RESOURCES



### PRIMARY CHARACTERISTICS

|   |                 |
|---|-----------------|
| $I_{F(AV)}$                             | 2 x 10 A        |
| $V_{RRM}$                               | 120 V           |
| $I_{FSM}$                               | 120 A           |
| $V_F$ at $I_F$ = 10 A ( $T_A$ = 125 °C) | 0.65 V          |
| $T_J$ max.                              | 175 °C          |
| Package                                 | SMPD (TO-263AC) |
| Circuit configuration                   | Common cathode  |

### TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection in commercial, industrial, and automotive application.

### MECHANICAL DATA

#### Case: SMPD (TO-263AC)

Molding compound meets UL 94 V-0 flammability rating  
Base P/N-M3 - halogen-free, RoHS-compliant  
Base P/NHM3 - halogen-free, RoHS-compliant, and AEC-Q101 qualified

**Terminals:** matte tin plated leads, solderable per J-STD-002 and JESD 22-B102  
M3 and HM3 suffix meets JESD 201 class 2 whisker test

**Polarity:** as marked

### MAXIMUM RATINGS ( $T_A$ = 25 °C unless otherwise noted)

| PARAMETER   | SYMBOL            | V20DM120C   | UNIT |
|---|-------------------|-------------|------|
| Maximum repetitive peak reverse voltage   | $V_{RRM}$         | 120         | V    |
| Maximum average forward rectified current (fig. 1)                                | $I_{F(AV)}$       | 20          | A    |
| per device  |                   | 10          |      |
| per diode   |                   |             |      |
| Peak forward surge current 10 ms single half sine-wave superimposed on rated load | $I_{FSM}$         | 120         | A    |
| Voltage rate of change (rated $V_R$ )   | $dV/dt$           | 10 000      | V/μs |
| Operating junction and storage temperature range                                  | $T_J$ , $T_{STG}$ | -40 to +175 | °C   |

| <b>ELECTRICAL CHARACTERISTICS</b> ( $T_A = 25^\circ\text{C}$ unless otherwise noted) |                       |                           |                      |      |      |               |  |
|--|-----------------------|---------------------------|----------------------|------|------|---------------|--|
| PARAMETER  | TEST CONDITIONS       |                           | SYMBOL               | TYP. | MAX. | UNIT          |  |
| Instantaneous forward voltage per diode  | $I_F = 5 \text{ A}$   | $T_A = 25^\circ\text{C}$  | $V_F$ <sup>(1)</sup> | 0.65 | -    | V             |  |
|  | $I_F = 10 \text{ A}$  |                           |                      | 0.85 | 0.93 |               |  |
|  | $I_F = 5 \text{ A}$   | $T_A = 125^\circ\text{C}$ |                      | 0.55 | -    |               |  |
|  | $I_F = 10 \text{ A}$  |                           |                      | 0.65 | 0.73 |               |  |
| Reverse current at rated $V_R$ per diode   | $V_R = 90 \text{ V}$  | $T_A = 25^\circ\text{C}$  | $I_R$ <sup>(2)</sup> | 23   | -    | $\mu\text{A}$ |  |
|  |                       | $T_A = 125^\circ\text{C}$ |                      | 1.6  | -    | $\text{mA}$   |  |
|  | $V_R = 120 \text{ V}$ | $T_A = 25^\circ\text{C}$  |                      | -    | 600  | $\mu\text{A}$ |  |
|  |                       | $T_A = 125^\circ\text{C}$ |                      | 3    | 20   | $\text{mA}$   |  |
|  |                       |                           |                      |      |      |               |  |

**Notes**

(1) Pulse test: 300  $\mu\text{s}$  pulse width, 1 % duty cycle

(2) Pulse test: Pulse width  $\leq 5 \text{ ms}$

| <b>THERMAL CHARACTERISTICS</b> ( $T_A = 25^\circ\text{C}$ unless otherwise noted) |            |   |     |  |                    |
|---|------------|---|-----|--|--------------------|
| PARAMETER   | SYMBOL     | V20DM120C                               |     |  | UNIT               |
| Typical thermal resistance  | per diode  | $R_{\theta\text{JC}}$                   | 2.8 |  | $^\circ\text{C/W}$ |
|   | per device |   | 1.5 |  |                    |
|   | per device | $R_{\theta\text{JA}}$ <sup>(1)(2)</sup> | 48  |  |                    |

**Notes**

(1) The heat generated must be less than the thermal conductivity from junction-to-ambient:  $dP_D/dT_J < 1/R_{\theta\text{JA}}$

(2) Free air, without heatsink

| <b>ORDERING INFORMATION</b> (Example) |                               |                 |              |               |                                    |
|---------------------------------------|-------------------------------|-----------------|--------------|---------------|------------------------------------|
| PACKAGE                               | PREFERRED P/N                 | UNIT WEIGHT (g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE                      |
| SMPD (TO-263AC)                       | V20DM120C-M3/I                | 0.55            | I            | 2000/reel     | 13" diameter plastic tape and reel |
| SMPD (TO-263AC)                       | V20DM120CHM3/I <sup>(1)</sup> | 0.55            | I            | 2000/reel     | 13" diameter plastic tape and reel |

**Note**

(1) AEC-Q101 qualified

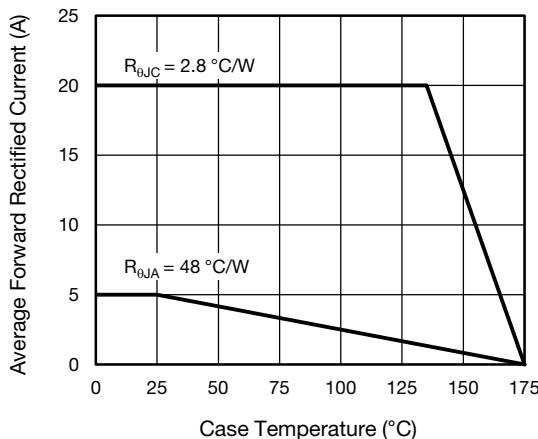
**RATINGS AND CHARACTERISTICS CURVES** ( $T_A = 25^\circ\text{C}$  unless otherwise noted)


Fig. 1 - Forward Current Derating Curve

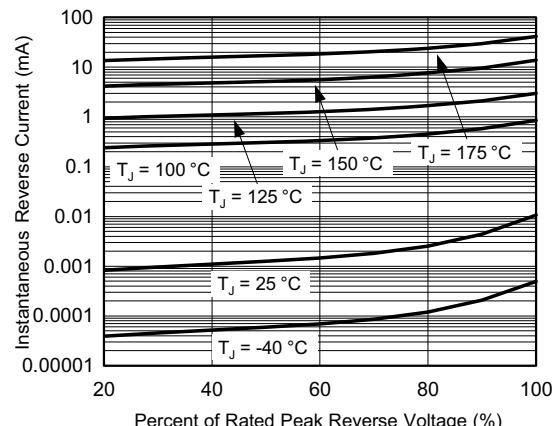


Fig. 4 - Typical Reverse Characteristics Per Diode

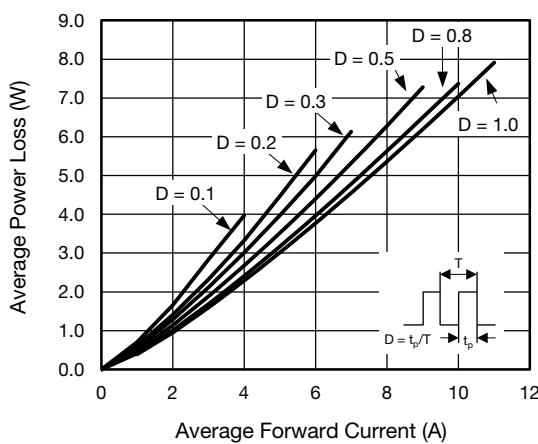


Fig. 2 - Forward Power Loss Characteristics Per Diode

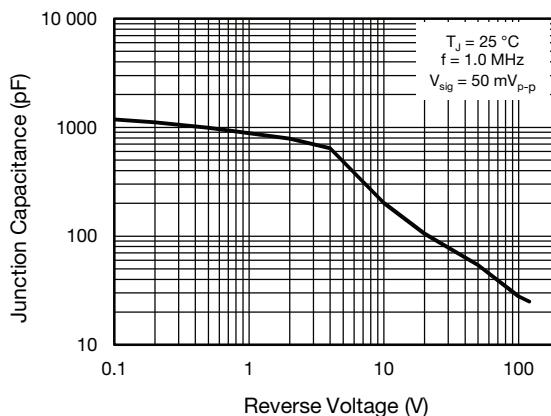


Fig. 5 - Typical Junction Capacitance Per Diode

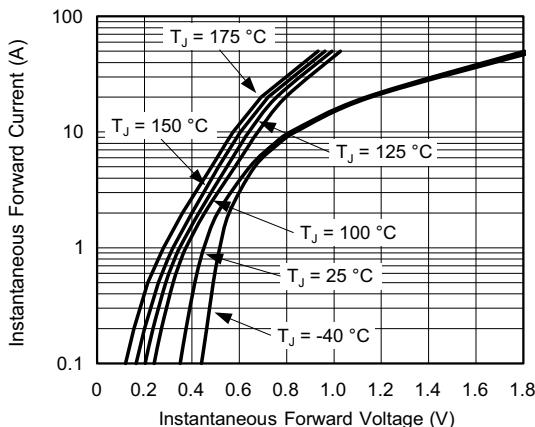


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

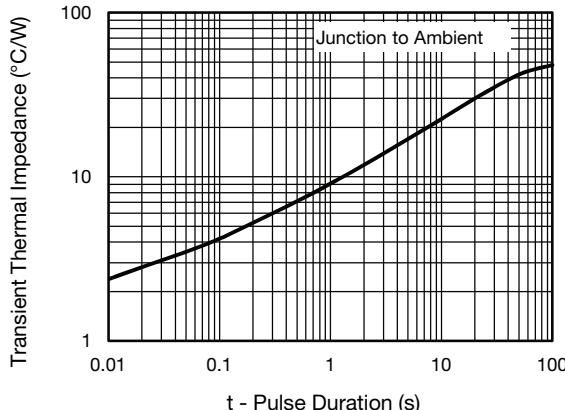


Fig. 6 - Typical Transient Thermal Impedance Per Device

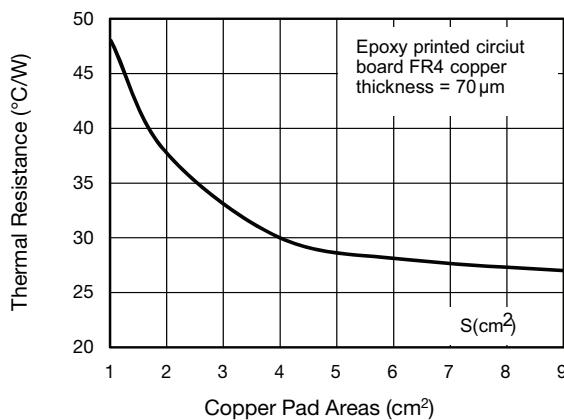
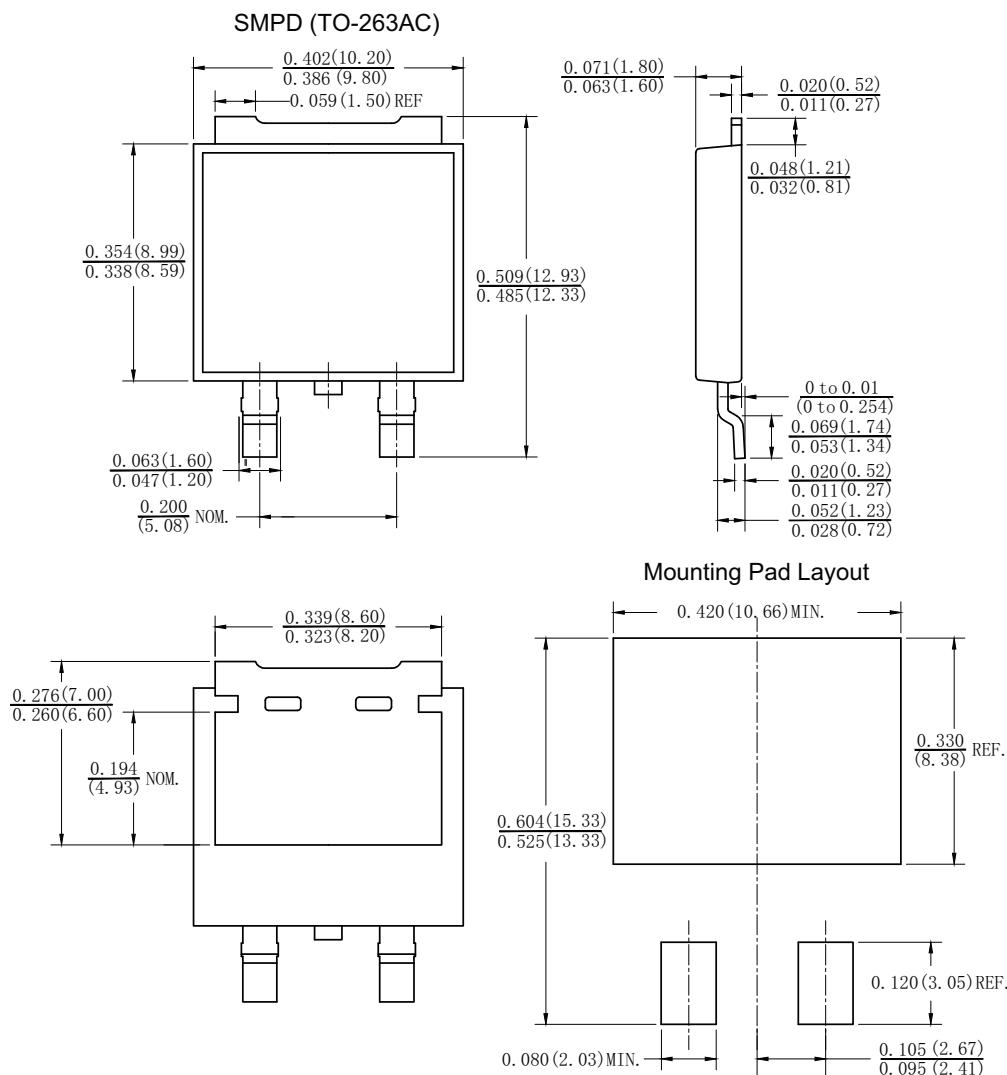


Fig. 7 - Thermal Resistance Junction-to-Ambient vs. Copper Pad Areas

### PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



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